

Schottky Barrier Diode

DB2G43200L1

For rectification

Features

• Low forward voltage VF

DB2G43200L1

- Forward current (Average) IF(AV) ≤ 2.0 A rectification is possible
- RoHS compliant
- (EU RoHS / MSL:Level 1 compliant)

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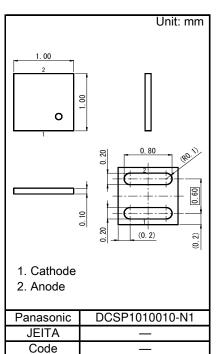
Marking Symbol: D8

Packaging

Embossed type (Thermo-compression sealing): 1 000 pcs / reel (standard)

Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Unit
Reverse Voltage *1	VR	-	40	V
Maximum Peak Reverse Voltage ^{*1}	VRM	-	40	V
Average Forward Current *2,3	IF(AV)	-	2.0	Α
Average Forward Current *2,4	IF(AV)	-	2.0	А
Non-repetitive Peak Surge Forward Current *1.5	IFSM	-	20	А
Operating Junction Temperature *6	Tj	-	150	С°
Ambient Temperature	Та	-40	+150	С°
Storage Temperature	Tstg	-55	+150	С°



Note) *1: Ta = Tj = 25°C

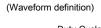
*2: Square wave : σ = 0.5

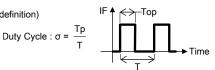
*3: Ta ≤ 38°C, when device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (608.0mm² area, 36µm thick).

*4: Solder Point Temperature : Tsp ≦ 130°C

*5: Square wave : Tp = 5 ms

*6: Power derating is necessary so that $Tj < 150^{\circ}C$.





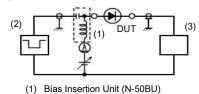
■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward Voltage	VF	IF = 2.0 A	-	0.45	0.52	V
Reverse Current	IR	VR = 40 V	-	90	400	μA
Terminal Capacitance	Ct	VR = 10 V, f = 1 MHz	-	47	-	pF
Reverse Recovery Time *1	trr	IF = IR = 100 mA, Irr = 10 mA	-	14	-	ns

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
2. This product is sensitive to electric shock (static electricity, etc.).

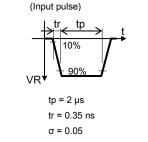
Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment. 3. *1: Measurement circuit, input pulse, output pulse for Reverse recovery time

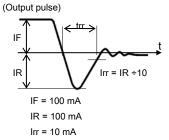
(Measurement circuit)



(2) Pulse Generator (PG-10N), RS = 50 Ω

(3) Wave Form Analyzer (SAS-8130), Ri = 50 Ω



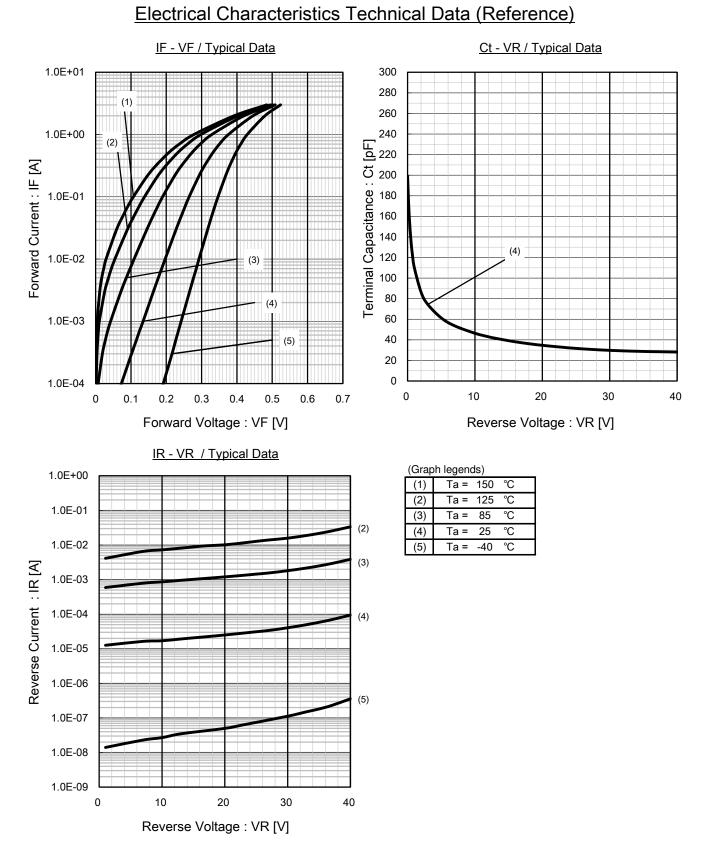


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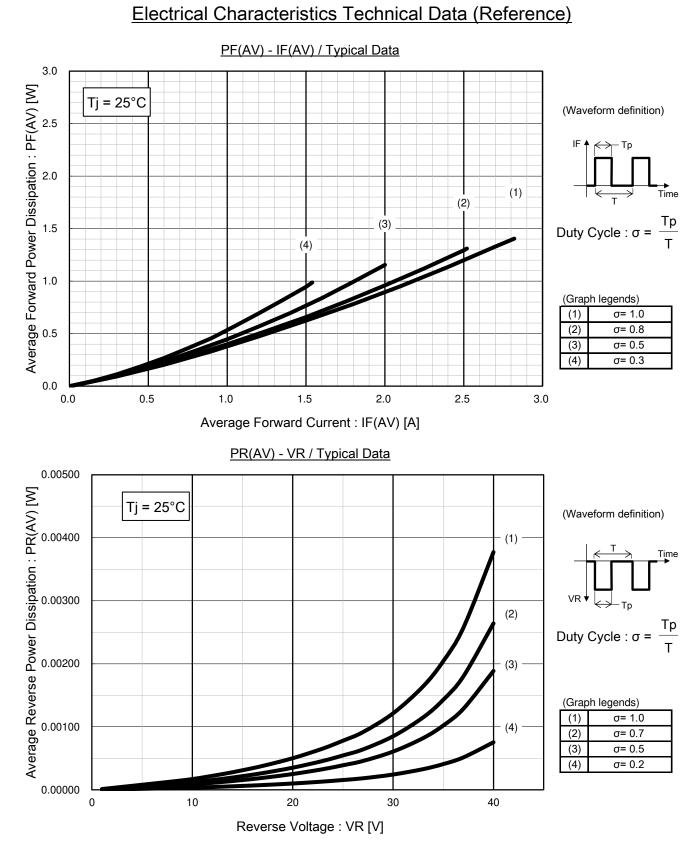


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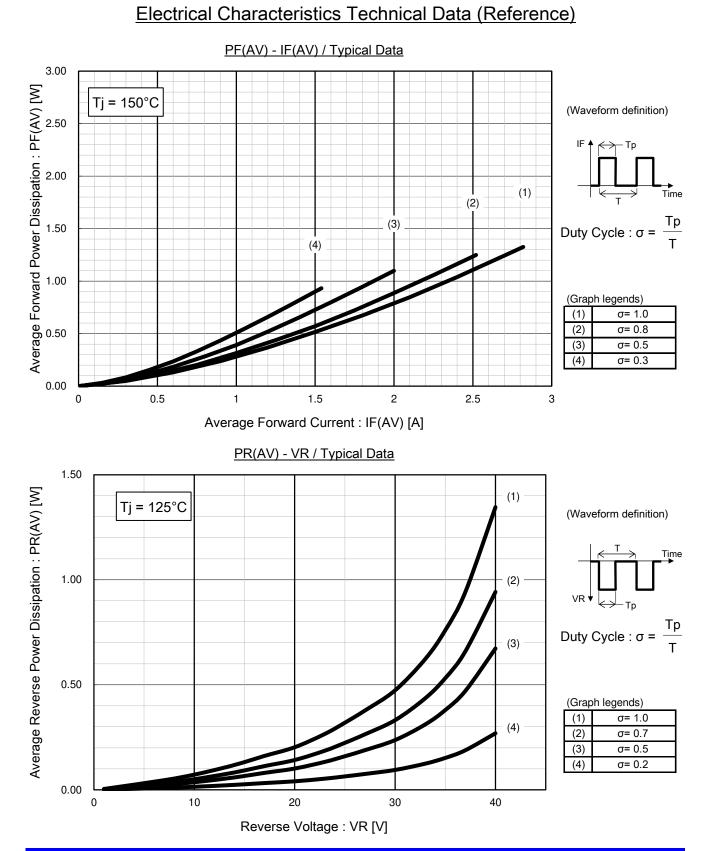
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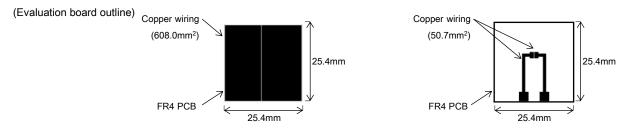
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Thermal Characteristics

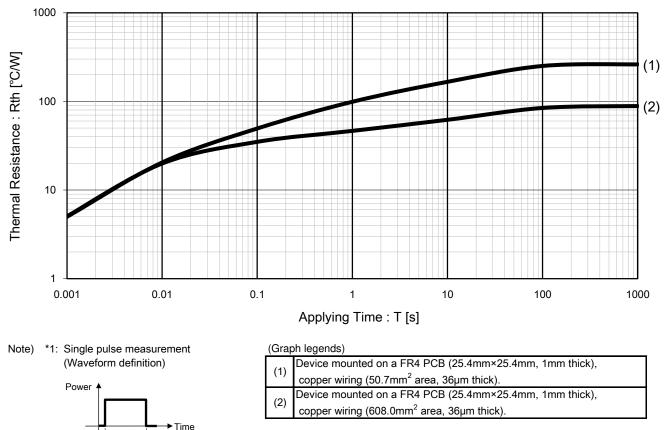
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Thermal Resistance, Junction to Solder Point	R _{th(j-sp)}	Ta = 25°C, in free air	-	15	-	°C/W
Thermal Resistance, Junction to Ambient ^{*1}	R _{th(j-a)}	Ta = 25°C, in free air	-	88	-	°C/W
Thermal Resistance, Junction to Ambient ^{*2}	R _{th(j-a)}	Ta = 25°C, in free air	-	262	-	°C/W

Note) *1: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (608.0mm² area, 36µm thick).

*2: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (50.7mm² area, 36µm thick).



Thermal Characteristics Technical Data (Reference)



Rth - T *1 / Typical Data

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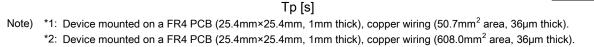
Applying Time : T

Doc No. TT4-ZZ-02050 Revision. 0

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Effective Transient Thermal Resistance - Tp *1 / Typical Data 1000 (Evaluation board outline) Effective Transient Thermal Resistance [°C/W] (Waveform definition) (1) 100 Power A (2) (3) (4) Duty Cycle : σ = 10 (5) (Graph legends) (6) $\sigma = 0.5$ (1)σ = 0.2 (2)(3) $\sigma = 0.1$ (4) σ = 0.05 1 (5) $\sigma = 0.02$ 1 0.0001 0.001 0.01 0.1 10 100 1000 (6) σ = 0 Tp [s] Effective Transient Thermal Resistance - Tp *2 / Typical Data 1000 (Evaluation board outline) Effective Transient Thermal Resistance [°C/W] (Waveform definition) 100 Power ♠ ← Tp (1) (2) Duty Cycle : σ = (3) 10 (4) (5) (Graph legends) (6) (1) $\sigma = 0.5$ σ = 0.2 (2) σ = 0.1 (3) σ = 0.05 (4) 1 (5) $\sigma = 0.02$ 0.0001 0.001 0.01 0.1 1 10 100 1000 (6) $\sigma = 0$

Thermal Characteristics Technical Data (Reference)



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Time

<u>Тр</u> Т

Time

<u>Тр</u> Т

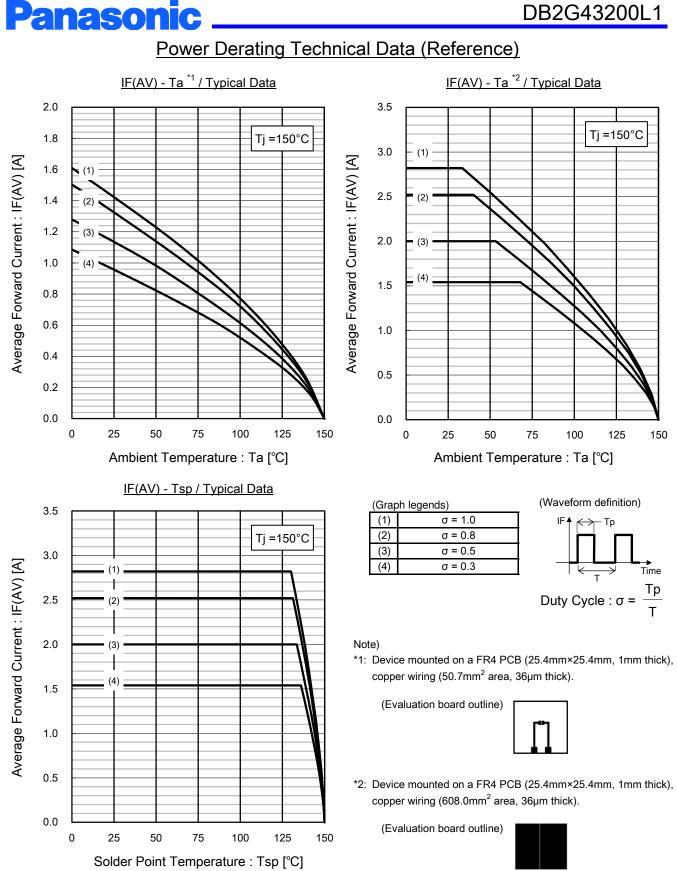
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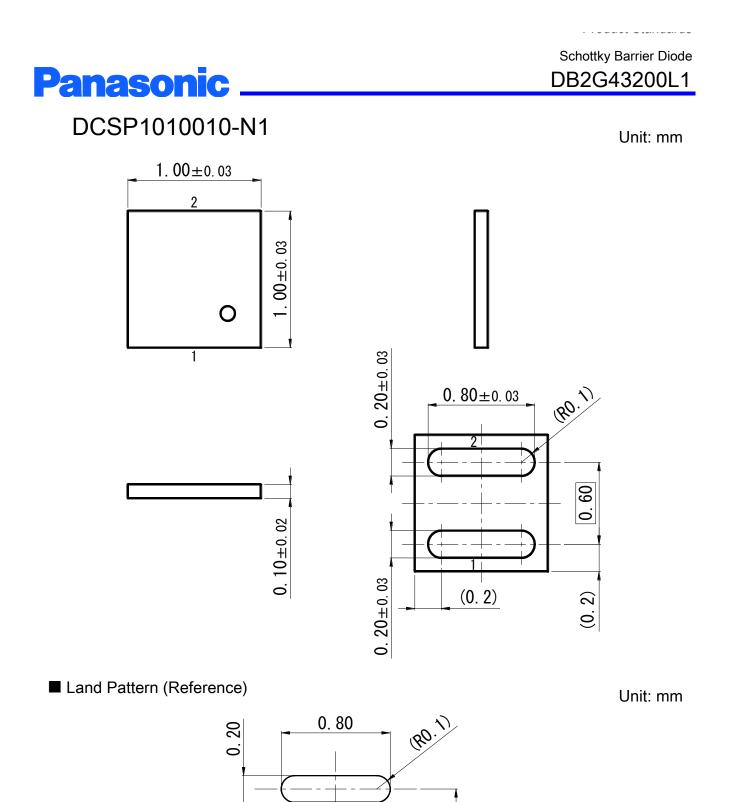
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0.60

0.20

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